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Diodes Incorporated ZXMN3A14FTA

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A Product Line of **Diodes Incorporated**



ZXMN3A14F

Product Summary

| BV _{DSS} | Max R _{DS(on)} | Max I _D T _A = 25°C (Note 4) |
|-------------------|-----------------------------|---|
| 201/ | $65m\Omega @ V_{GS} = 10V$ | 3.2A |
| 30V | $95m\Omega @ V_{GS} = 4.5V$ | 2.6A |

Description and Applications

This MOSFET utilizes a unique structure that combines the benefits of low on-resistance with fast switching speed, making it ideal for high-efficiency power management applications.

DC - DC converters

- Power management functions
- **Disconnect switches**
- Motor control

ee Green

30V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low on-resistance
- Fast switching speed
- Low gate charge
- Low threshold
- Totally Lead-Free & Fully RoHS compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

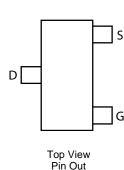
Mechanical Data

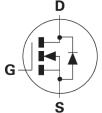
- Case: SOT23 •
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper leadframe Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (approximate)



SOT23

Top View





Equivalent Circuit

Ordering Information (Note 3)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|---------|--------------------|-----------------|-------------------|
| ZXMN3A14FTA | 314 | 7 | 8 | 3000 Units |

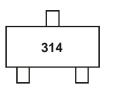
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

3. For more packaging details, go to our website at http://www.diodes.com.

Marking Information

Notes:



314 = Product Type Marking Code







ZXMN3A14F

Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | | | Symbol | Value | Units | |
|---|----------------|---------------------|----------------------------------|------------------|-------------------|---|
| Drain-Source Voltage | | | | V _{DSS} | 30 | V |
| Gate-Source Voltage | | | V _{GS} | ±20 | V | |
| Continuous Drain Current | $V_{GS} = 10V$ | $T_A = 70^{\circ}C$ | (Note 5) (Note 5) (Note 4) | ID | 3.9 3.2 3.2 | A |
| Pulsed Drain Current (Note 6) | | | | I _{DM} | 18 | A |
| Continuous Source Current (Body Diode) (Note 5) | | | Is | 2.3 | А | |
| Pulsed Source Current (Body Diode) (Note 6) | | | I _{SM} | 18 | A | |

Thermal Characteristics @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|--|----------------------------------|-------------|-------|
| Power Dissipation (Note 4) | PD | 1 | W |
| Linear Derating Factor | FD | 8 | mW/°C |
| Power Dissipation (Note 5) | D - | 1.5 | W |
| Linear Derating Factor | PD | 12 | mW/°C |
| Thermal Resistance, Junction to Ambient (Note 4) | R _{θJA} | 125 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{θJA} | 83 | °C/W |
| Thermal Resistance, Junction to Leads (Note 7) | R _{θJL} | 70.44 | °C/W |
| Operating and Storage Temperature Range | T _{J,} T _{STG} | -55 to +150 | C° |

Notes:

4. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions

For a device surface mounted on FR4 PCB measured at 1 55 secs.
Repetitive rating 25mm x 25mm FR4 PCB, D=0.02 pulse width=300µs - pulse current limited by maximum junction temperature.

7. Thermal resistance from junction to solder-point (at the end of the drain lead).

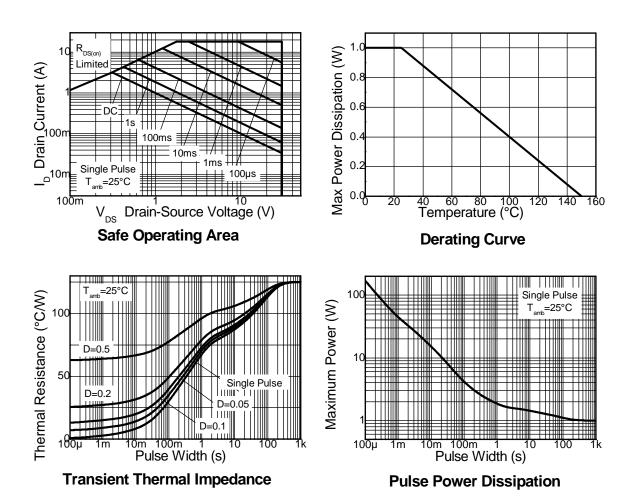




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Thermal Characteristics



ZXMN3A14F Document Number DS33536 Rev. 2 - 2





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ZXMN3A14F

| Electrical Characteristics @T _A = 25 | 5°C unless otherw | vise specif | ied | | | |
|---|----------------------|-------------|------|------|------|---|
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | _ | _ | V | $I_D = 250 \mu A, V_{GS} = 0 V$ |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | _ | 1 | μΑ | $V_{DS} = 30V, V_{GS} = 0V$ |
| Gate-Source Leakage | I _{GSS} | _ | _ | ±100 | nA | $V_{GS} = \pm 12V, V_{DS} = 0V$ |
| ON CHARACTERISTICS | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 1.0 | _ | 2.2 | V | $I_D = 250 \mu A$, $V_{DS} = V_{GS}$ |
| Static Drain-Source On-Resistance (Note 8) | D | | 48 | 65 | mΩ | $V_{GS} = 10V, I_D = 3.2A$ |
| Static Drain-Source On-Resistance (Note 8) | R _{DS} (ON) | _ | 69 | 95 | | $V_{GS} = 4.5V, I_D = 2.6A$ |
| Forward Transconductance (Notes 8 and 10) | g _{fs} | _ | 7.1 | _ | S | V _{DS} = 15V, I _D = 3.2A |
| Diode Forward Voltage (Note 8) | V _{SD} | _ | 0.85 | 0.95 | V | $T_J = 25^{\circ}C$, $I_S = 2.5A$, $V_{GS} = 0V$ |
| Reverse Recovery Time (Note 10) | t _{rr} | _ | 13 | _ | ns | T _J = 25°C, I _F = 1.6A, |
| Reverse Recovery Charge (Note 10) | Qrr | _ | 7 | _ | nC | di/dt = 100A/µs |
| DYNAMIC CHARACTERISTICS (Note 10) | | | | | | |
| Input Capacitance | C _{iss} | _ | 448 | _ | | V _{DS} = 15V, V _{GS} = 0V f = 1.0MHz |
| Output Capacitance | Coss | _ | 82 | _ | pF | |
| Reverse Transfer Capacitance | Crss | _ | 49 | — | | |
| Turn-On Delay Time (Note 9) | t _{D(on)} | _ | 2.4 | _ | | $\label{eq:VDD} \begin{split} V_{DD} &= 15V, \ I_D = 1A, \\ R_G &\cong 6.0\Omega, \ V_{GS} = 10V \end{split}$ |
| Turn-On Rise Time (Note 9) | tr | _ | 2.5 | _ | | |
| Turn-Off Delay Time (Note 9) | t _{D(off)} | _ | 13.1 | _ | ns | |
| Turn-Off Fall Time (Note 9) | tf | | 5.3 | _ | | |
| Total Gate Charge (Note 9) | Qg | _ | 8.6 | _ | | 14 4514 14 4014 |
| Gate-Source Charge (Note 9) | Q _{gs} | | 1.4 | _ | nC | $V_{DS} = 15V, V_{GS} = 10V,$ $I_{D} = 3.2A$ |
| Gate-Drain Charge (Note 9) | Q _{gd} | | 1.8 | _ | | |

Notes:

8. Measured under pulsed conditions. Pulse width = 300 μ s. Duty cycle ≤ 2%. Switching characteristics are independent of operating junction temperature.
For design aid only, not subject to production testing.

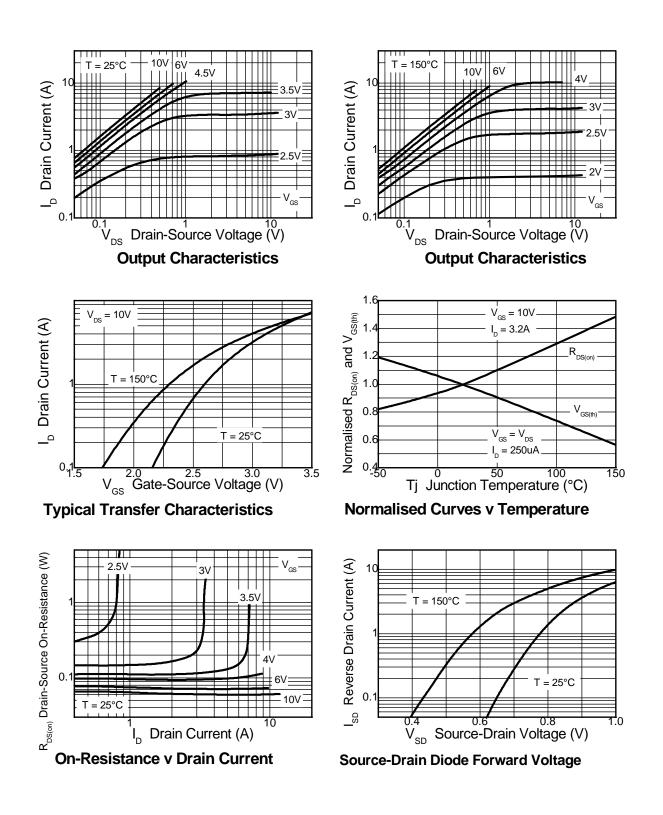




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Typical Characteristics





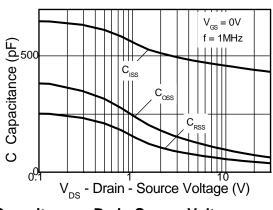


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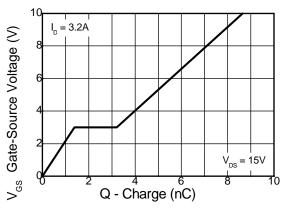




Typical Characteristics - continued

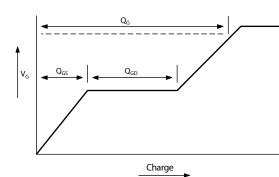




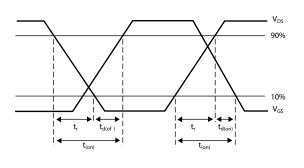


Gate-Source Voltage v Gate Charge

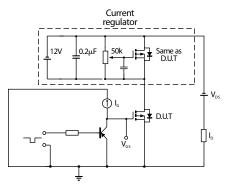
Test Circuits



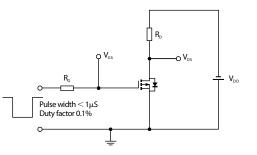
Basic gate charge waveform



Switching time waveforms



Gate charge test circuit



Switching time test circuit

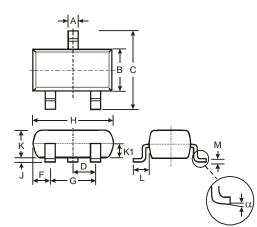






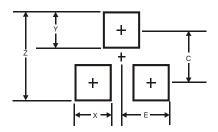


Package Outline Dimensions



| SOT23 | | | | | |
|----------------------|-------|------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.37 | 0.51 | 0.40 | | |
| В | 1.20 | 1.40 | 1.30 | | |
| С | 2.30 | 2.50 | 2.40 | | |
| D | 0.89 | 1.03 | 0.915 | | |
| F | 0.45 | 0.60 | 0.535 | | |
| G | 1.78 | 2.05 | 1.83 | | |
| н | 2.80 | 3.00 | 2.90 | | |
| J | 0.013 | 0.10 | 0.05 | | |
| K | 0.903 | 1.10 | 1.00 | | |
| K1 | - | - | 0.400 | | |
| L | 0.45 | 0.61 | 0.55 | | |
| Μ | 0.085 | 0.18 | 0.11 | | |
| α | 0° | 8° | - | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| Х | 0.8 |
| Y | 0.9 |
| С | 2.0 |
| E | 1.35 |







ZXMN3A14F

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